

MS14N60

900V N-Channel MOSFET

Description

The MS14N60 is a N-channel enhancement-mode MOSFET, providing the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost effectiveness. The TO-220 package is universally preferred for all commercial-industrial applications

Features

- Low On Resistance
- Simple Drive Requirement
- Low Gate Charge
- Fast Switching Characteristic
- RoHS compliant package

Application

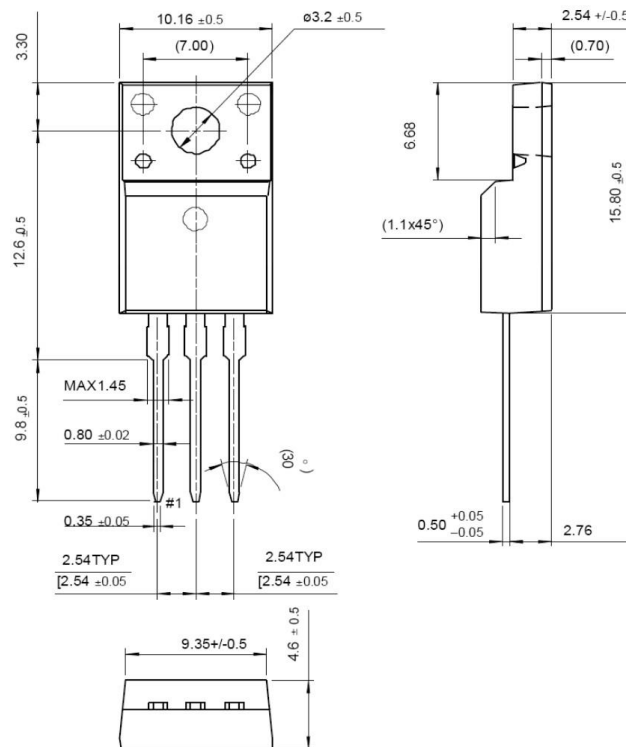
- Adapter
- Switching Mode Power Supply

Packing & Order Information

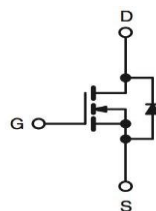
50/Tube ; 1,000/Box



RoHS
COMPLIANT



Graphic symbol



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_{DSS}	Drain-Source Voltage	600	V
V_{GS}	Gate-Source Voltage	± 30	V
I_D	Drain Current -Continuous (TC=25°C)	14	A
	Drain Current -Continuous (TC=100°C)	8.4	A
I_{DM}	Drain Current -Pulsed	56	A
I_{AR}	Avalanche Current	14	A
E_{AS}	Single Pulsed Avalanche Energy	53	mJ
E_{AR}	Repetitive Avalanche Energy	16	mJ
dV/dt	Peak Diode Recovery dV/dt	4.5	V/ns
T_J	Storage Temperature	150	°C
P_D	Power Dissipation (TC=25°C)	60	W
	Derate above 25C	0.35	W/°C

- Drain current limited by maximum junction temperature

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Absolute Maximum Ratings (Tc=25°C unless otherwise specified)

Symbol	Parameter	Value	Unit
T _{STG}	Operating Junction and Storage Temperature	-55 to +150	°C
T _L	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds	300	°C

Note:

1. Repetitive rating; pulse width limited by maximum junction temperature.
2. I_{AS}=14A, V_{DD}=50V, L=0.5mH, R_G=25Ω, starting TJ=+25°C.
3. I_{SD}≤7.5A, dI/dt≤100A/μs, VDD≤BVDSS, starting TJ=+25°C.

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Units
R _{θJC}	Thermal Resistance , Junction-to-Case	--	2.58	°C/W
R _{θJA}	Thermal Resistance , Junction-to-Ambient	--	62.5	

Static Characteristics

Symbol	Parameter	Test Conditions	Min	Typ.	Max.	Units
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250μA	2.0		4.0	V
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V , I _D = 250μA	600	--	--	V
ΔBV _{DSS} /ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250μA, Referenced to 25°C	--	0.7	--	V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 600 V , V _{GS} = 0 V V _{DS} = 480 V , T _C = 125°C	--	--	1 10	uA
I _{GSS}	Gate-Body Leakage Current, Forward	V _{DS} = ±30	--	--	±100	nA
*R _{DS(ON)}	Static Drain-Source On-Resistance	V _{GS} = 10 V , I _D = 8.4 A	--	--	0.55	Ω

Dynamic Characteristics

Symbol	Parameter	Test Conditions	Min	Typ.	Max.	Units
C _{ISS}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V, f=1.0MHz	--	2222	--	pF
C _{OSS}	Output Capacitance		--	180	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	17	--	pF
t _{d(on)}	Turn-On Time	V _{DD} = 250 V, I _D = 14 A, V _{GS} = 10 V , R _G = 9.1 Ω	--	16	--	ns
t _r	Turn-On Time		--	30	--	ns
t _{d(off)}	Turn-Off Delay Time		--	48	--	ns
t _f	Turn-Off Fall Time		--	34	--	ns

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Dynamic Characteristics

Symbol	Parameter	Test Conditions	Min	Typ.	Max.	Units
Q_g	Total Gate Charge	$V_{DD} = 250\text{ V}, I_D = 14\text{ A},$ $V_{GS} = 10\text{ V}$	--	40	--	nC
Q_{gs}	Gate-Source Charge		--	10	--	nC
Q_{gd}	Gate-Drain Charge		--	15	--	nC

Source-Drain Diode

Symbol	Parameter	Test Conditions	Min	Typ.	Max.	Units
I_S		$V_D = V_G = 0,$ $V_S = 1.3\text{ V}$	--	--	14	A
I_{SM}			--	--	56	
V_{SD}		$I_S = 14\text{ A}, V_{GS} = 0\text{ V}$	--	--	1.5	V
t_{rr}		$I_S = 14\text{ A}, V_{GS} = 0\text{ V}$ $diF/dt = 100\text{ A}/\mu\text{s}$	--	393	--	ns
Q_{rr}			--	3529	--	μC

*Pulse Test : Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

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